










| | |
|---|--|
|  | <h2>S5K-E3/9AT</h2> |
| | <p>Hersteller-Teilenummer: S5K-E3/9AT</p> <hr/> <p>Hersteller / Marke: Vishay / Semiconductor - Diodes Division</p> <hr/> <p>Teil der Beschreibung: DIODE GEN PURP 800V 5A DO214AB</p> <hr/> <p>Datenblätter:  S5K-E3/9AT.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 15000 pcs Stock Available.</p> <hr/> <p>Lieferrn von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

| | |
|------------------------------------|---|
| Teilenummer | S5K-E3/9AT |
| Hersteller | Vishay / Semiconductor - Diodes Division |
| Beschreibung | DIODE GEN PURP 800V 5A DO214AB |
| Kategorie | Diskrete Halbleiterprodukte > Dioden-Gleichrichter- |
| Teilstatus | 15000 pcs Stock |
| Serie | - |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | DO-214AB, SMC |
| Supplier Device-Gehäuse | DO-214AB, (SMC) |
| Diodentyp | Standard |
| Strom - Richt (Io) | 5A |
| Spannung - Forward (Vf) (Max) @ If | 1.15V @ 5A |
| Strom - Sperrleckstrom @ Vr | 10µA @ 800V |
| Spannung - Sperr (Vr) (max) | 800V |
| Geschwindigkeit | Standard Recovery >500ns, > 200mA (Io) |
| Rückwärts-Erholzeit (Trr) | 2.5µs |
| Betriebstemperatur - Anschluss | -55°C ~ 150°C |
| Kapazität @ Vr, F | 40pF @ 4V, 1MHz |
| Verpackung | Tape & Reel (TR) |

S5K-E3/9AT ist neu im Original, Suche S5K-E3/9AT Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie S5K-E3/9AT Vishay / Semiconductor - Diodes Division mit Garantie und Vertrauen. Anfrage S5K-E3/9AT: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|--|---|--|
|  <p>S5K V7G TSC (Taiwan Semiconductor) DIODE GEN PURP 800V 5A DO214AB</p> |  <p>S5K-M3/57T Vishay / Semiconductor - Diodes Division DIODE GPP 5A 800V DO-214AB</p> |  <p>S5K-M3/9AT Electro-Films (EFI) / Vishay DIODE GPP 5A 800V DO-214AB</p> |  <p>S5K-M3/57T Electro-Films (EFI) / Vishay DIODE GPP 5A 800V DO-214AB</p> |
|  <p>S5K V6G TSC (Taiwan Semiconductor) DIODE GEN PURP 800V 5A DO214AB</p> |  <p>S5K-M3/9AT Vishay / Semiconductor - Diodes Division DIODE GPP 5A 800V DO-214AB</p> |  <p>S5K-E3/9AT Electro-Films (EFI) / Vishay DIODE GEN PURP 800V 5A DO214AB</p> |  <p>S5K-E3/57TVISHAY VISHAY VISHAY SMC</p> |

heiße Teile

Mehr

| | | | | |
|--------------------|--------------------|--------------------|---------------------|-----------------|
| AOZ1017AI | CC1812JKNPOEBN101 | CL10B472KC85PNC | CPH5617-TL | CPV362M4N |
| CX24110-11 | DMG2307L-7-F | D DSC557-0344SI1 | EMK316ABJ226ML-T | FUSB302UCX |
| GJM1555C1H9R5BB01D | GRM0336S1E8R0DD01D | GRM188C81E475KE11D | IRF830ASTRL | IXFH52N30Q |
| IXGH120N30C3 | LMK316BJ226KL-T | LMV822Q1MMX/NOBP | MBM29PL160BD-75PFTN | MMBT4403WT1G |
| NCP18WF104J03RB | NLCV32T-331K-PF | PCA9509D | PK55F-160//120 | QM2518C1 |
| RKZ33BKGP1 | RT9166-33GVL | D S5K-E3/57T | S5K-E3/57T | S5K-E3/9AT |
| S5K-M3/57T | D S5K-M3/57T | S5K1N1FX13-GGR0 | S5K2P1YX45-U382 | S5K3H1GX33-FGX2 |
| S5K3H1GXD1 | S5K6A1GX04 | S5K6AAF03 | S5K6AAF03-2T83 | S5K3DFXA5-2T83 |
| S5KC-13-F | SI2315BDS-T1-E3 | SKKD380/02 | TC7106CPL | TESDT5V0ARFG |
| TIBPAL16L8-5CFN | UMK212SD822JD-T | VI-J6P-IZ | WPD56-16 | Z8623012SSC |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited